

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Divisional U.S. Patent Application of:

Glen FOX, et al.

Serial No.

Filed: July 15, 2003

Title: A CHARGE PUMP OR OTHER CHARGE
STORAGE CAPACITOR INCLUDING PZT
LAYER FOR COMBINED USE AS AN
ENCAPSULATE LAYER AND DIELECTRIC
LAYER OF A FERROELECTRIC
CAPACITOR AND A METHOD OF
MANUFACTURING THE SAME

Examiner:

Art Unit:

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
Alexandria, VA 22313-1450


Sir:

Pursuant to 37 C.F.R. § 1.97 the Examiner may wish to consider the references listed on the attached Form PTO/SB/08A. In submitting these references for the Examiner's consideration, no representation is made or implied that the references are or are not material to the examination of the application. The Examiner is encouraged to make his or her own determination of materiality.

Each of these references were either cited or provided in U.S. Patent Application Serial No. 09/862,365, and/or U.S. Patent Application Serial No. 09/862,365, from which priority under 35 U.S.C. § 120 is claimed. Pursuant to 37 C.F.R. § 1.98, copies of the references are not provided.

No fee is believed due. However, any fees associated with this communication may be charged to Deposit Account No. 50-1123.

Respectfully submitted,

A handwritten signature in black ink, appearing to read 'CW Burton', with a long horizontal line extending to the right.

July 15, 2003

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PTO/SB/08A (10/01) (Substitute for form 1449A/PTO) INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary) Sheet <u> 1 </u> of <u> 1 </u>	ATTY. DOCKET NO. RAM 482 DIV2 Client/Matter No. 80412.0135.002	APPLICATION NO.
	FIRST NAMED INVENTOR: Glen FOX	
	FILING DATE: July 15, 2003	ART UNIT:

U.S. PATENT DOCUMENTS

Examiner Initials	Cite No.	Document No. No. – Kind Code	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Doc	
		3,935,083	01-27-1976	Tomozawa et al.	
		5,266,821	11-30-1993	Chern et al.	
		5,024,964	06-18-1991	Rohrer et al.	
		5,350,705	09-27-1994	Brassington et al.	
		5,031,144	07-09-1991	Persky	
		5,338,951	08-16-1994	Argos et al.	
		5,206,788	04-1993	Larson et al.	
		5,920,453	07-1999	Evans et al.	
		6,010,927	01-2000	Jones et al.	
		5,475,248	12-1995	Takenaka, Kazuhiro	
		5,789,303	08-1998	Leung et al.	
		6,521,927	02-2003	Hidaka et al.	
		5,481,490	01-1996	Watanabe et al.	
		5,638,319	06-1997	Onishi et al.	

FOREIGN PATENT DOCUMENTS

Examiner Initials	Cite No.	Foreign Patent Doc entry code – No. – Kind Code	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Doc	Pages, Columns. Lines Where Relevant Passages or Relevant Figures Appear	TRANSLATION	
		0-449-484-A1	03-30-1990	EPO			
		0 415 751 A1	06-03-1991	EPO			
		5-267557	01-19-1994	Japan			
		2-260559	01-08-1991	Japan			
		5-135999 A	01-06-1993	Japan			

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS

Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s) publisher, city and/or country where published
		Liu et al., "Low-Temperature Fabrication of Amorphous BaTiO ₃ Thin-Film Bypass Capacitors," IEEE Device Letters (1993) 14:320-322

EXAMINER SIGNATURE

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.